NSN 5961-01-079-3295

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View Online at https://aerobasegroup.com/nsn/5961-01-079-3295 **Inclosure Material:** Metal **Overall Length:** Between 1.553 inches and 1.573 inches **Overall Height:** 0.762 inches **Overall Width:** 1.050 inches **Mounting Facility Quantity: Internal Configuration:** Junction contact Joint Electronic Device Engineering Council/jedec/case Outline Designation: To-3 **Mounting Method:** Unthreaded hole **Features Provided:** Hermetically sealed case **Semiconductor Material:** Silicon Voltage Rating In Volts Per Characteristic: 40.0 breakdown voltage, collector-to-emitter, base open **Current Rating Per Characteristic:** 30.00 amperes source cutoff current and 2.00 milliamperes zero-gate-voltage source current preset **Power Rating Per Characteristic:** 150.0 watts small-signal input power, common-collector absolute **Maximum Operating Tempurature Per Measurement Point:** 175.0 degrees celsius junction **Special Features:** Junction pattern arrangement: npn **Terminal Type And Quantity:** 1 case and 2 pin Shelf Life: N/a **Unit Of Measure: Demilitarization:** Yes - demil/mli

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